SCLS383C - SEPTEMBER 1997 - REVISED MAY 2000

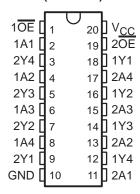
- EPIC™ (Enhanced-Performance Implanted CMOS) Process
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 3.3 V, T_A = 25°C
- 2-V to 5.5-V V_{CC} Operation
- Support Mixed-Mode Voltage Operation on All Ports
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (DW, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Packages, Chip Carriers (FK), and DIPs (J)

description

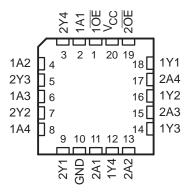
These octal buffers/line drivers are designed for 2-V to 5.5-V V_{CC} operation.

The 'LV244A devices are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

SN54LV244A . . . J OR W PACKAGE SN74LV244A . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



SN54LV244A . . . FK PACKAGE (TOP VIEW)



These devices are organized as two 4-bit line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LV244A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LV244A is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each buffer)

INP	JTS	OUTPUT
OE	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

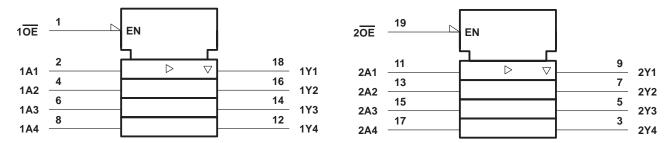


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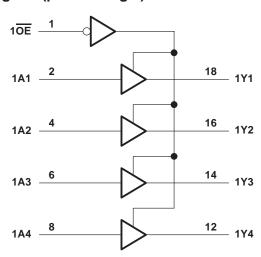
TEXAS INSTRUMENTS

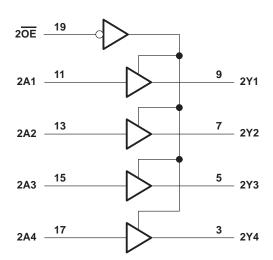
logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





SN54LV244A, SN74LV244A OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	0.5 V to 7 V
Output voltage range applied in the high or low state, VO (see No	otes 1 and 2)0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)	
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	
Continuous output current, I_O ($V_O = 0$ to V_{CC})	
Continuous current through V _{CC} or GND	
Package thermal impedance, θ_{JA} (see Note 3): DB package	
	92°C/W
	58°C/W
	60°C/W
Storage temperature range, T _{stg}	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. This value is limited to 5.5 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



SN54LV244A, SN74LV244A OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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recommended operating conditions (see Note 4)

			SN54L\	SN54LV244A		V244A	UNIT
			MIN	MAX	MIN	MAX	UNII
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
\ ,,	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} ×0.7		$V_{CC} \times 0.7$		V
VIH	r light-lever input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	V _{CC} ×0.7		$V_{CC} \times 0.7$		V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$V_{CC} \times 0.7$		$V_{CC} \times 0.7$		
		V _{CC} = 2 V		0.5		0.5	
\ \/	Low lovel input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$,	√CC×0.3		V _{CC} ×0.3	V
VIL	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$,	√CC×0.3	,	V _{CC} ×0.3	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$,	√CC×0.3	,	$V_{CC} \times 0.3$	
٧ _I	Input voltage		0	5.5	0	5.5	V
\/ -	Output voltage	High or low state	0	Усс	0	Vсс	V
Vo		3-state	0	5.5	0	5.5	V
		V _{CC} = 2 V	1	- 50		-50	μА
	High-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	20	-2		-2	
ЮН	High-level output current	V _{CC} = 3 V to 3.6 V	Q	-8		-8	mA
		V _{CC} = 4.5 V to 5.5 V		-16		-16	
		V _{CC} = 2 V		50		50	μА
l	Low lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
lOL	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		8		8	mA
		V _{CC} = 4.5 V to 5.5 V		16		16	
		V _{CC} = 2.3 V to 2.7 V	0	200	0	200	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V	0	100	0	100	ns/V
		V _{CC} = 4.5 V to 5.5 V	0	20	0	20	
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	,,	SN54LV244A	SN74LV244A	UNIT
PARAMETER	TEST CONDITIONS	VCC	MIN TYP MAX	MIN TYP MAX	UNIT
	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.1	V _{CC} -0.1	
\/a+	$I_{OH} = -2 \text{ mA}$	2.3 V	2	2	V
VOH	I _{OH} = -8 mA	3 V	2.48	2.48	V
	I _{OH} = -16 mA	4.5 V	3.8	3.8	
	I _{OL} = 50 μA	2 V to 5.5 V	0.1	0.1	
\/a-	I _{OL} = 2 mA	2.3 V	0.4	0.4	V
VOL	I _{OL} = 8 mA	3 V	0.44	0.44	V
	I _{OL} = 16 mA	4.5 V	0.55	0.55	
lį	$V_I = V_{CC}$ or GND	0 V to 5.5 V	\$ ±1	±1	μΑ
loz	$V_O = V_{CC}$ or GND	5.5 V	±5	±5	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	20	20	μΑ
loff	V_I or $V_O = 0$ to 5.5 V	0 V	5	5	μΑ
C _i	V _I = V _{CC} or GND	3.3 V	2.3	2.3	pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

	_				_						
PARAMETER	FROM	то	LOAD	T _A = 25°C		SN54LV244A		SN74LV244A		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
^t pd	А	Υ			7.5*	12.5*	1*	15*	1	15	
t _{en}	ŌĒ	Υ	C _L = 15 pF		8.9*	14.6*	1*	17*	1	17	ns
^t dis	ŌĒ	Y			9.1*	14.1*	1*	16*	1	16	
t _{pd}	А	Υ			9.5	15.3	1/-	18	1	18	
t _{en}	ŌĒ	Y	C. 50 pF		10.8	17.8)77 _C	21	1	21	
^t dis	ŌĒ	Y	C _L = 50 pF		13.4	19.2	Q 1	21	1	21	ns
tsk(o)						2	Y			2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM TO LOA		LOAD T _A = 25°C		SN54LV244A		SN74L	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Υ			5.4*	8.4*	1*	10*	1	10	
t _{en}	ŌĒ	Y	C _L = 15 pF		6.3*	10.6*	1*	12.5*	1	12.5	ns
^t dis	ŌĒ	Y			7.6*	11.7*	1*	13*	1	13	
t _{pd}	А	Υ			6.8	11.9	1/	13.5	1	13.5	
ten	ŌĒ	Υ	C 50 pF		7.8	14.1	⁷ 7 _C	16	1	16	20
^t dis	ŌĒ	Υ	C _L = 50 pF		11	16	Q ² 1	18	1	18	ns
tsk(o)]			1.5	Q			1.5	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Վ = 25° C	;	SN54L	V244A	SN74L	V244A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Υ			3.9*	5.5*	1*	6.5*	1	6.5	
t _{en}	ŌE	Υ	C _L = 15 pF		4.5*	7.3*	1*	8.5*	1	8.5	ns
^t dis	ŌĒ	Υ			6.5*	12.2*	1*	13.5*	1	13.5	
^t pd	А	Υ			4.9	7.5	1/-	8.5	1	8.5	
t _{en}	ŌĒ	Υ	C: - 50 pF		5.6	9.3	770	10.5	1	10.5	no
^t dis	ŌE	Υ	C _L = 50 pF		8.8	14.2	0 1	15.5	1	15.5	ns
tsk(o)						1	Y			1	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, $V_{CC} = 3.3 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 5)

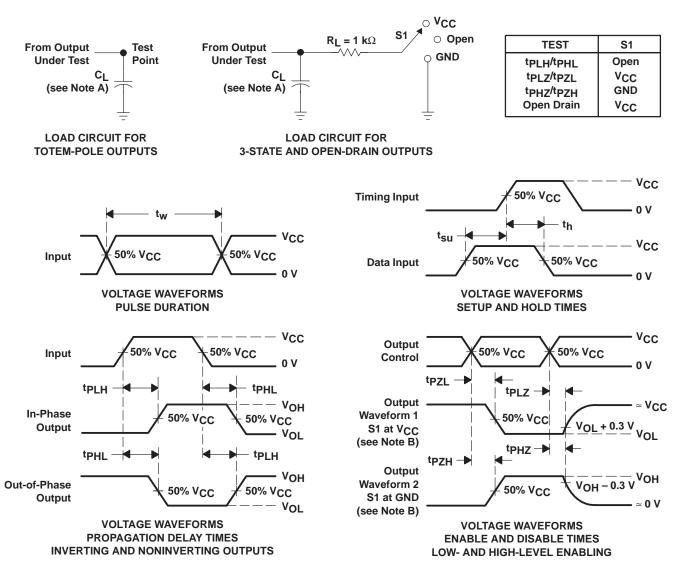
	PARAMETER		SN74LV244A			
	PARAMETER	MIN TYP MAX 0.55 -0.5		UNIT		
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.55		V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.5		V	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.9		V	
V _{IH(D)}	High-level dynamic input voltage	2.31			V	
V _{IL(D)}	Low-level dynamic input voltage			0.99	V	

NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST CO	VCC	TYP	UNIT	
Card	Power dissipation capacitance	$C_1 = 50 pF$	f = 10 MHz	3.3 V	14	PΓ
Cpd	Power dissipation capacitance	CL = 50 pr,	1 = 10 101112	5 V	16	PΓ

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_Q = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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